



Unit 1 –

SEMICONDUCTOR DIODES

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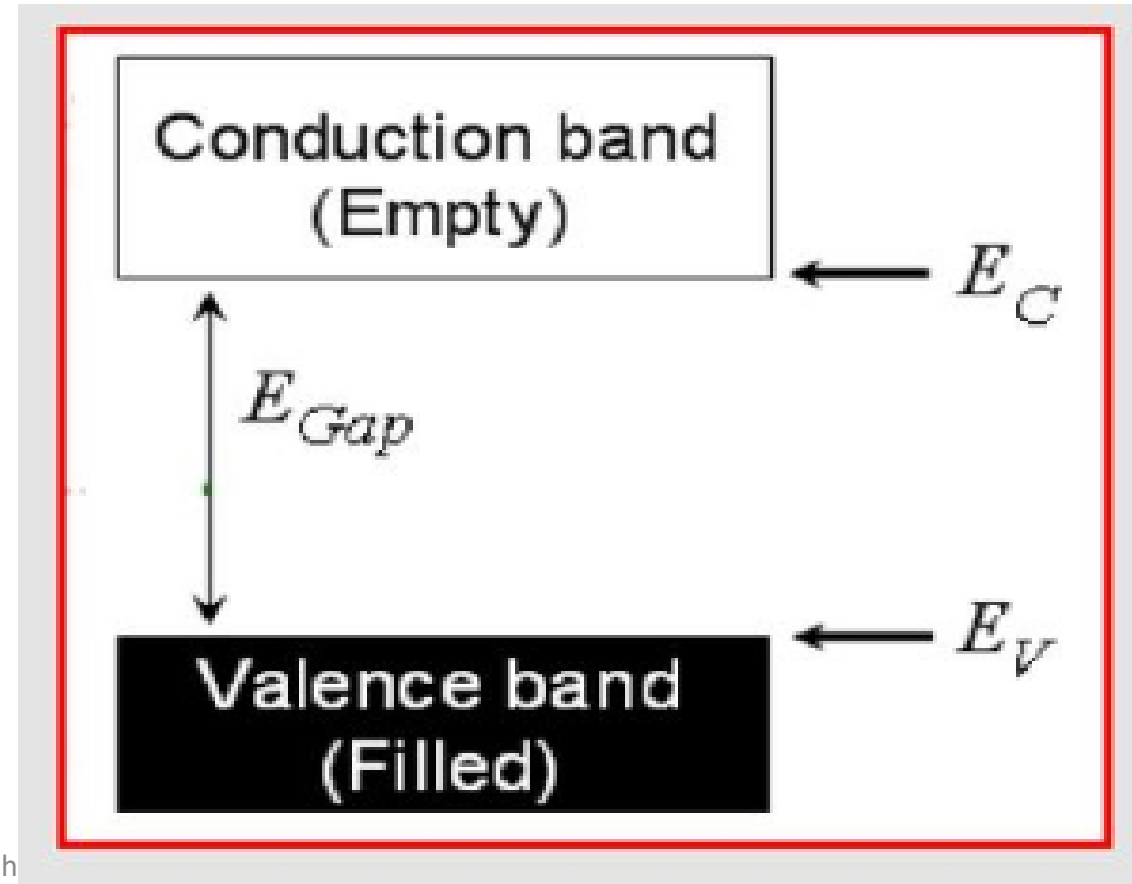
Class 1

Metals, Semiconductors and Insulators

Insulator

1. In Insulator - the Energy BandGap (E_g) is wider between Conduction Band and Valence Band.
Diamond -- $E_g = 5\text{eV}$
2. If electric field applied, the electrons in Valence Band (VB) cannot reach Conduction Band.

Energy Diagram of Insulator

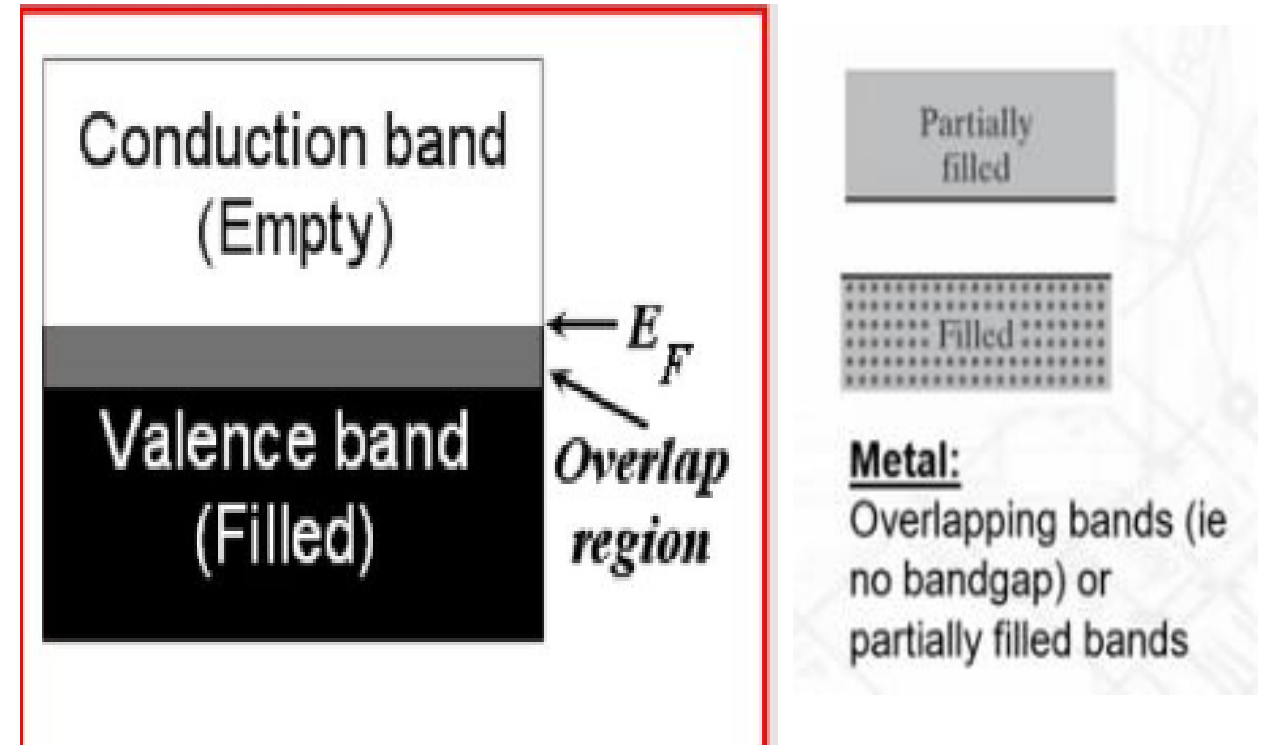


Metals, Semiconductors and Insulators

Metals

1. In Metals, valence band and conduction band overlap each other. Therefore, there is no forbidden gap in a conductor or partially filled conduction band
2. A small amount of applied external energy provides enough energy for the valence band electrons to move in to conduction band.

Energy Diagram of Metals



Metals, Semiconductors and Insulators

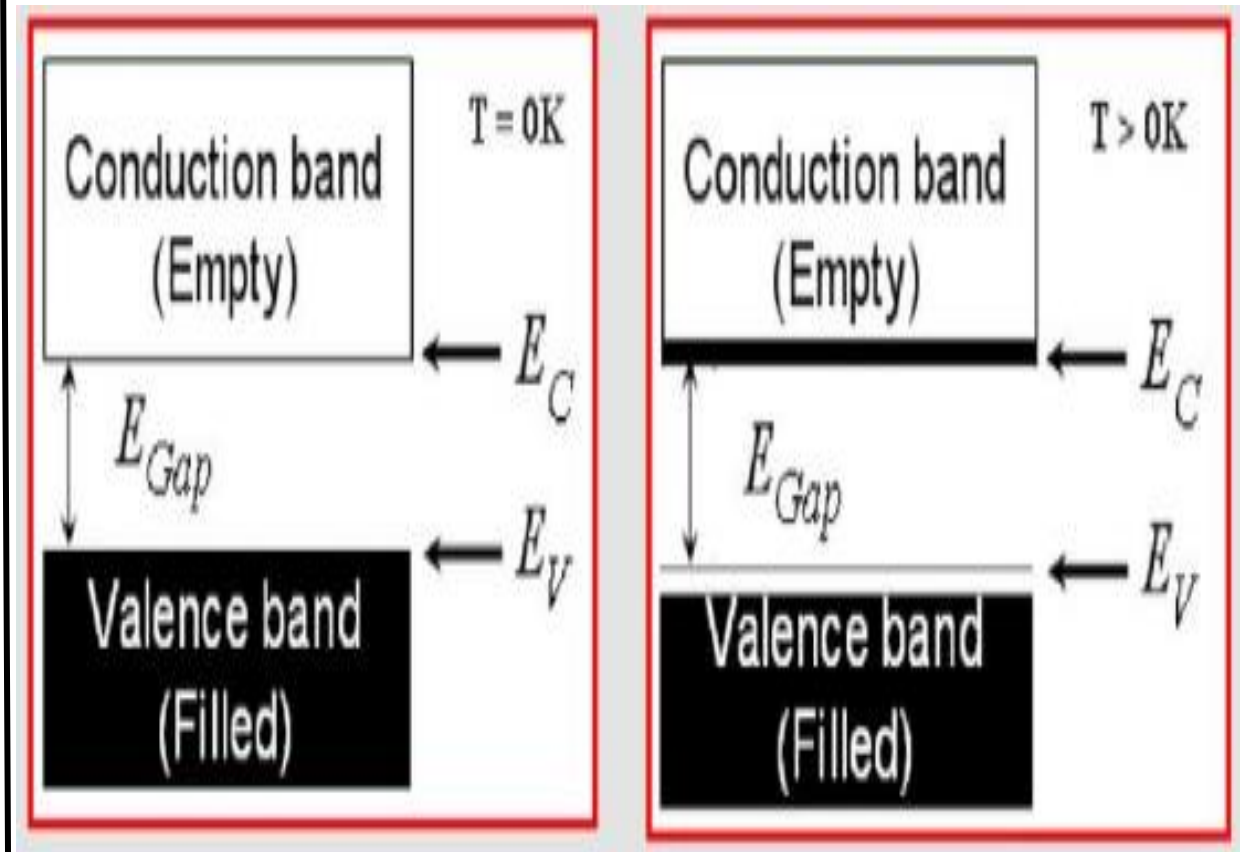
Semiconductor

1. In Semiconductor - the Energy BandGap (E_g) is smaller between Conduction Band and Valence Band than in insulators.

Si -- $E_g = 1.1\text{eV}$

2. At 0K , Semiconductor behave as an Insulator.
3. At $T > 0\text{K}$, Semiconductor behave as an Metal

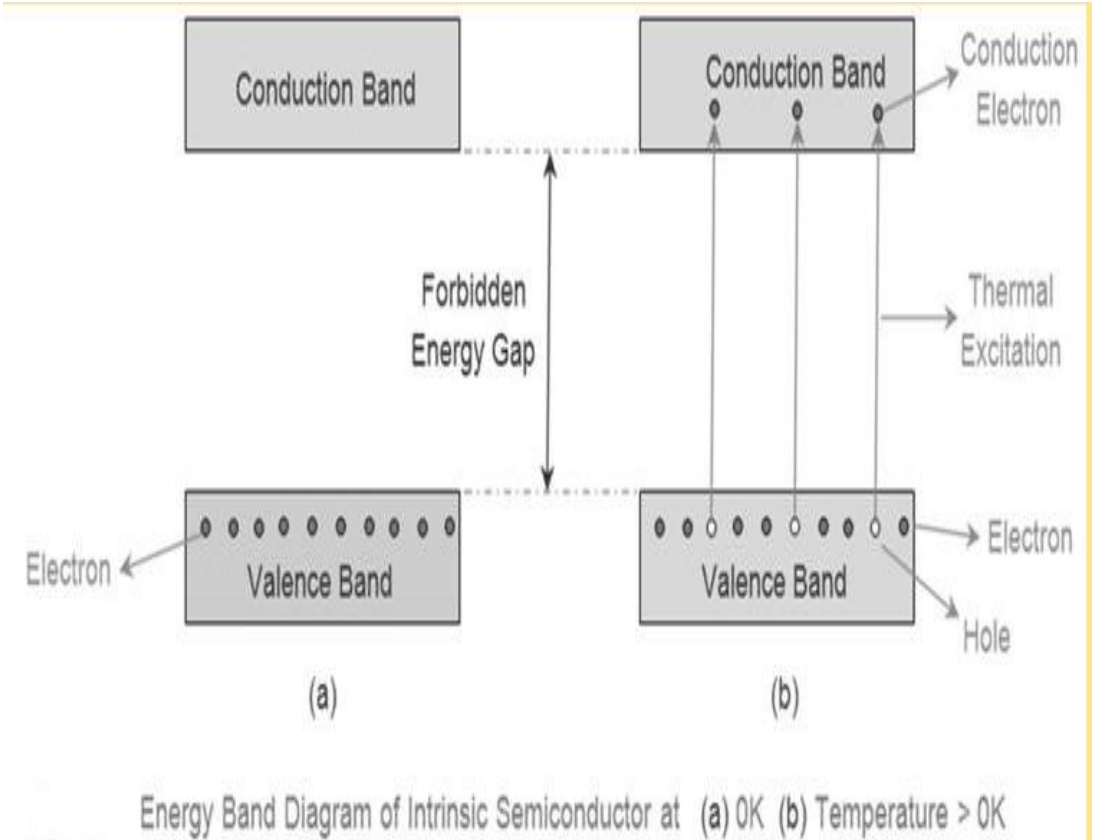
Energy Diagram of Semiconductor



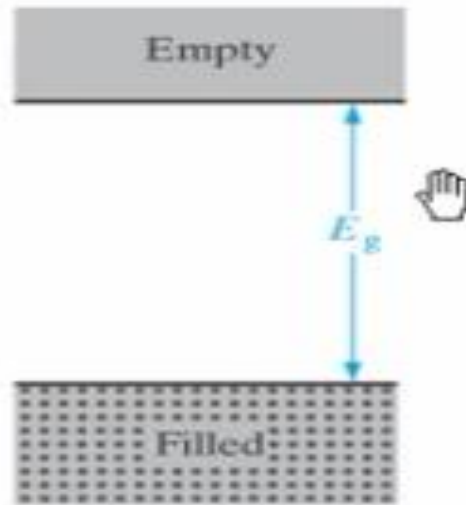
Metals, Semiconductors and Insulators

Semiconductor

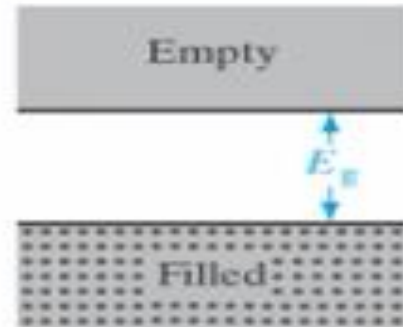
1. A small fraction of the electrons is thermally excited into the conduction band. These electrons carry current just as in metals.
2. The smaller the gap the more electrons in conduction band at a given temperature.
3. Resistivity decreases with temperature due to higher concentration of electrons in conduction band



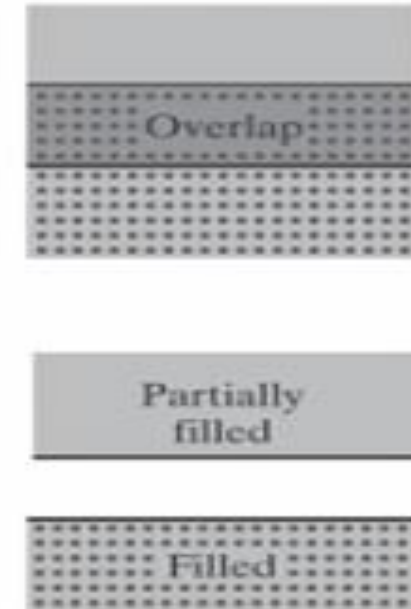
The Energy Band of Metals, Semiconductors and Insulators



Insulator:
One filled band, one empty band, large bandgap



Semiconductor:
Same as insulator except smaller bandgap

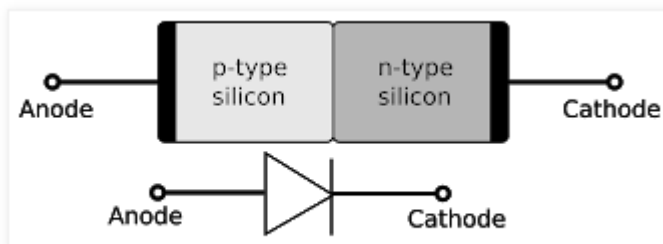


Metal:
Overlapping bands (ie no bandgap) or partially filled bands

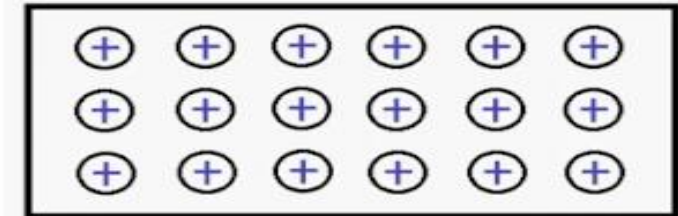
PN JUNCTION DIODE

What is a PN Junction?

A PN junction is a device formed by joining p-type (doped with B, Al) with n-type (doped with P, As, Sb) semiconductors and separated by a thin junction is called PN Junction diode or junction diode.

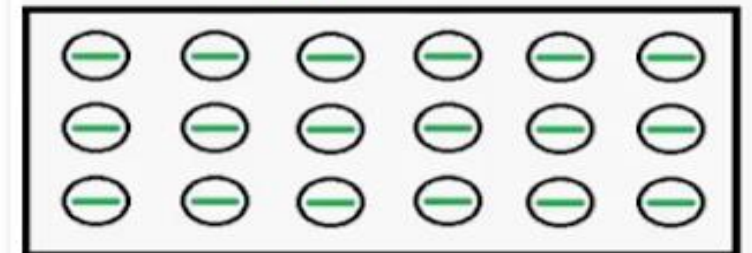


P TYPE



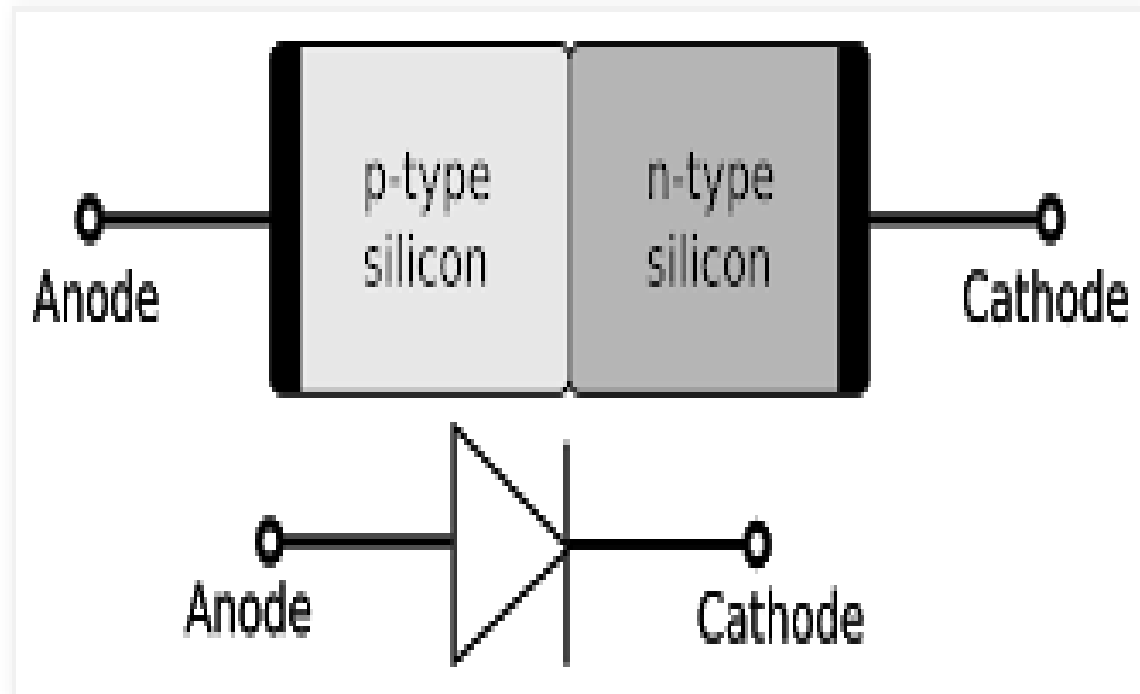
P-Type Semiconductor

N TYPE



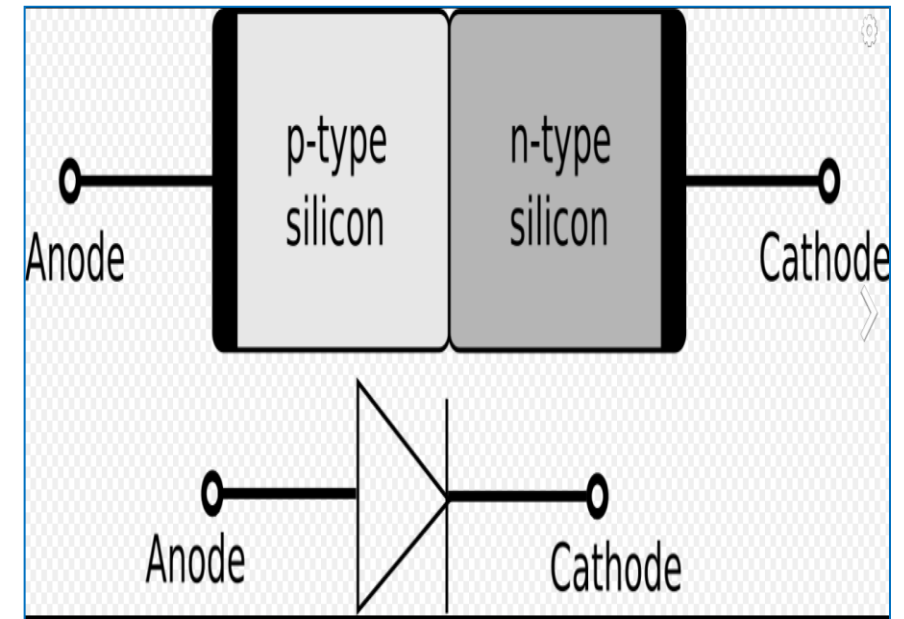
N-type Semiconductor

The PN Junction Diode



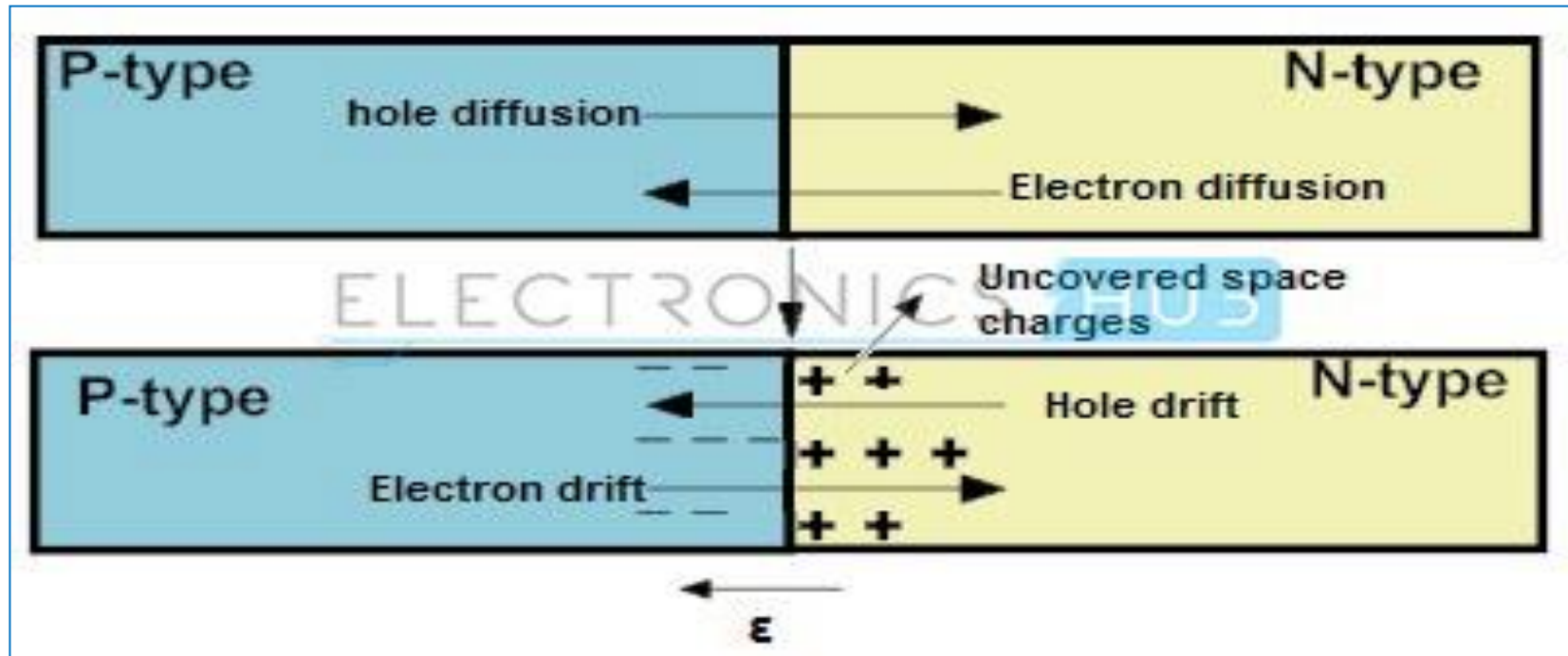
PN JUNCTION DIODE

- In PN junction diode, N is at right and P is at left.
- Majority carriers
N region -- electrons
P region -- holes



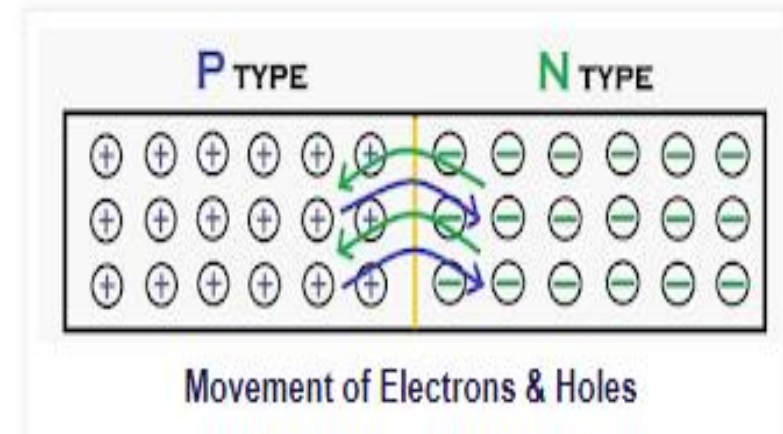
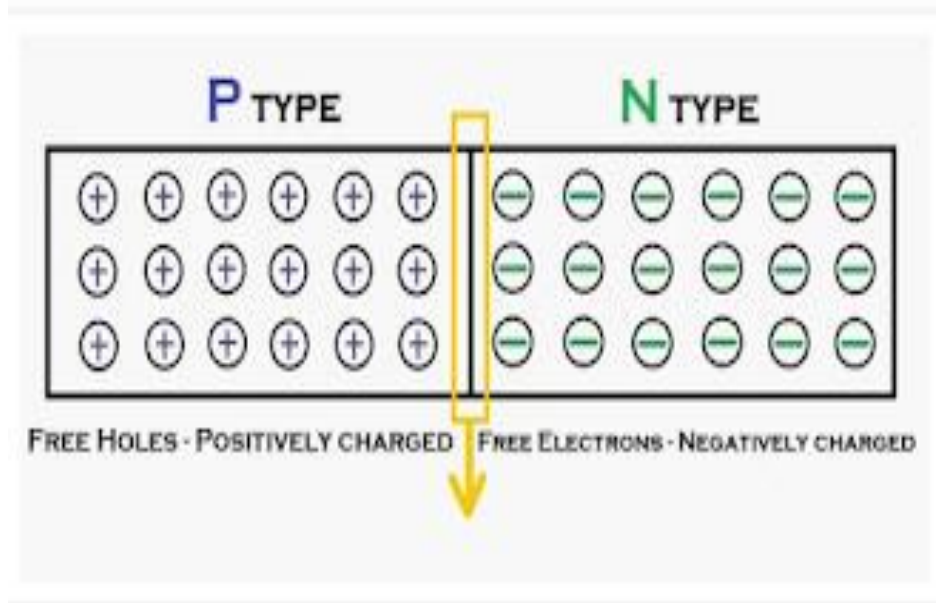
PN JUNCTION DIODE

Formation of depletion layer

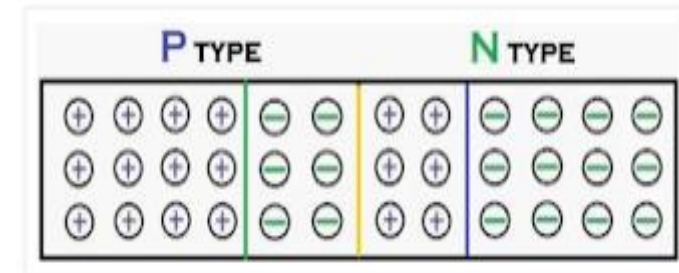
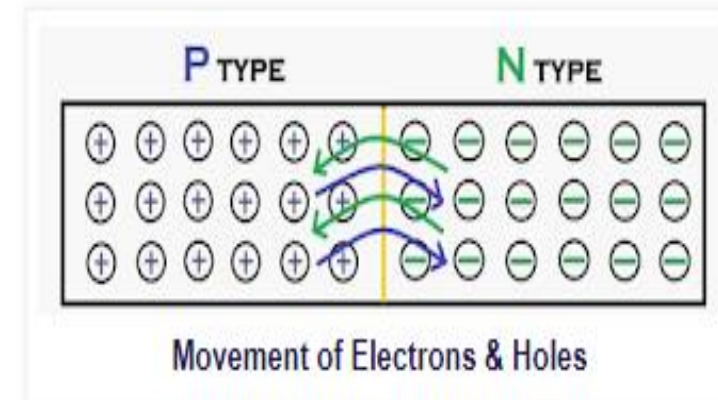
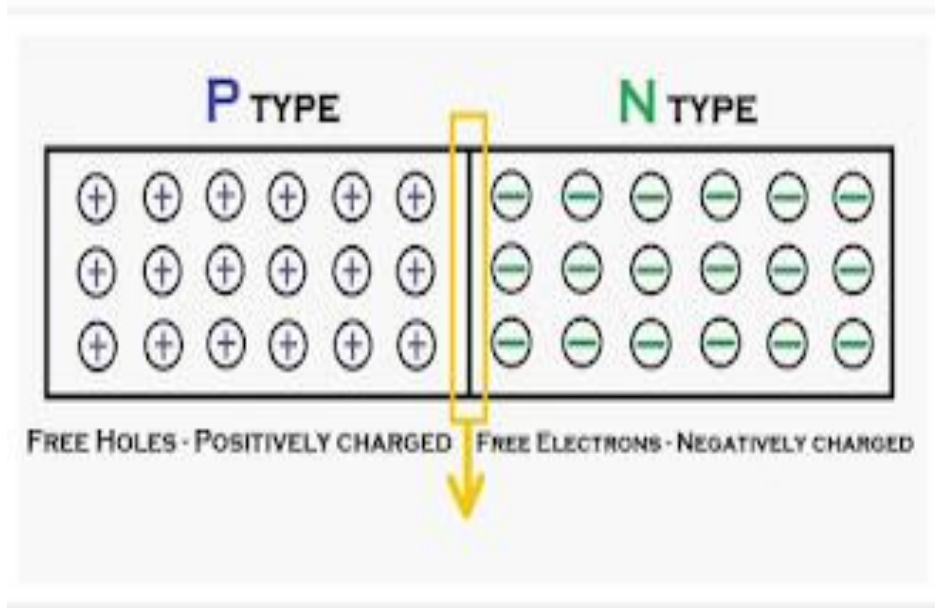


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The PN Junction Diode

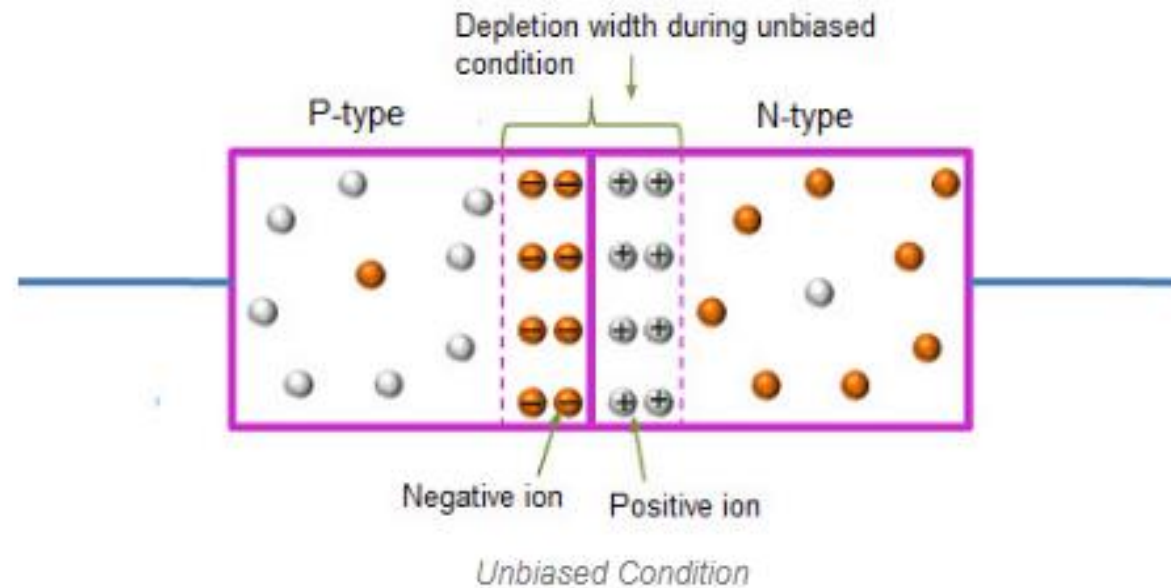


The PN Junction Diode



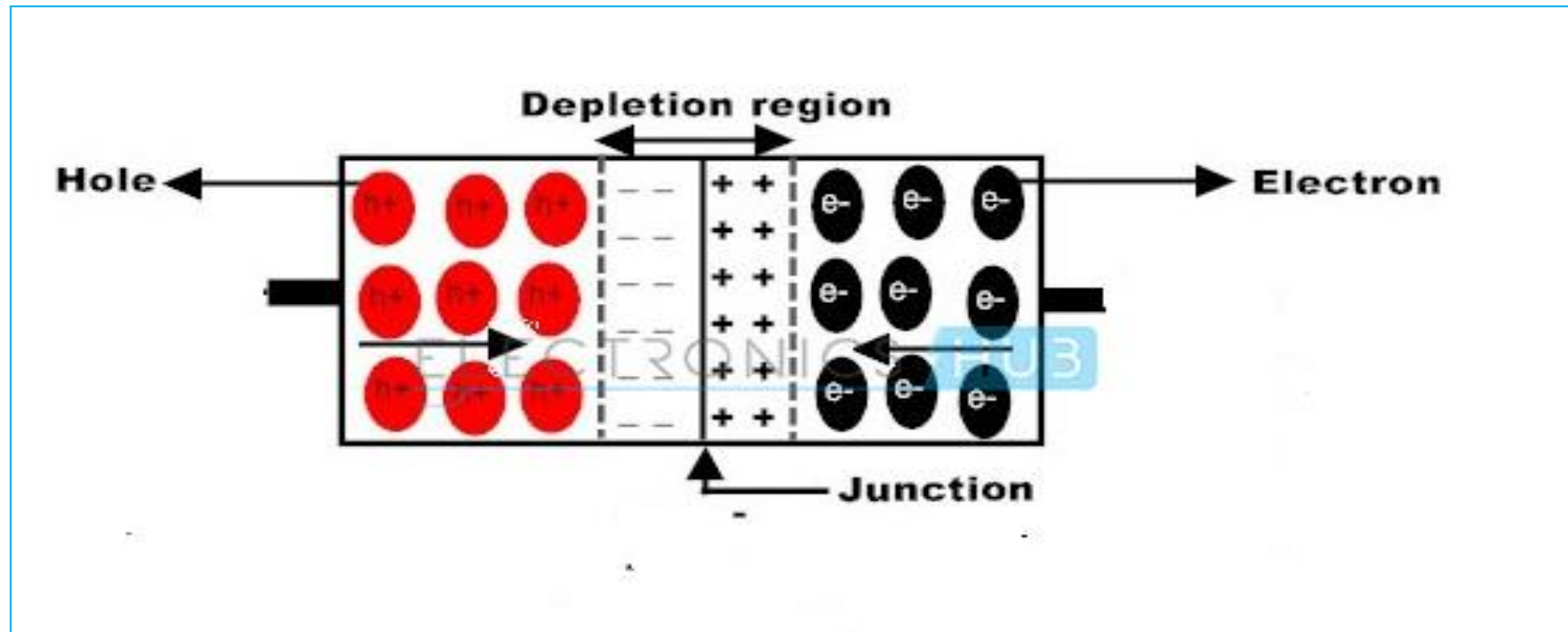
The PN Junction

- The PN Junction Diode UnBiased



PN JUNCTION DIODE

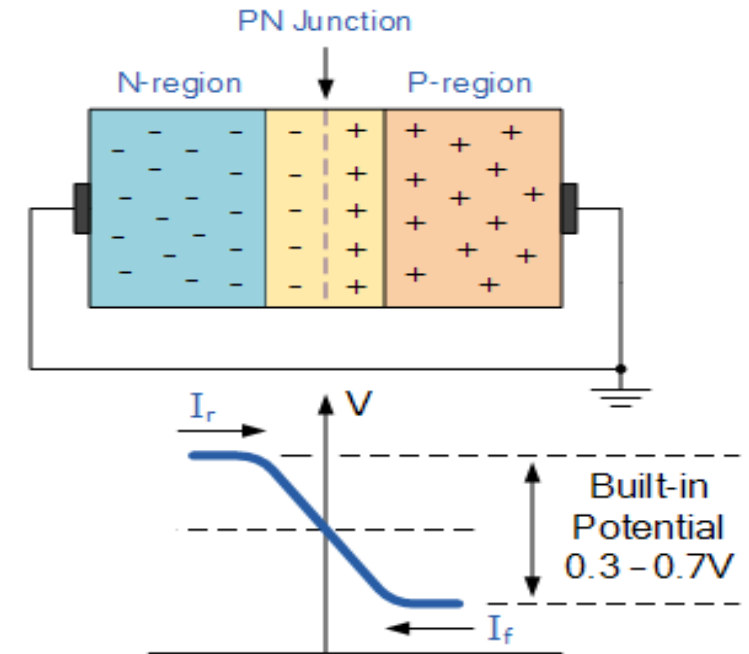
Formation of depletion layer



PN JUNCTION DIODE

POTENTIAL BARRIER

- The electrons in the N region have to climb the potential hill in order to reach the P region
- Electrons trying to cross from the N region to P region experience a retarding field of the battery and therefore repelled. Similarly for holes from P region.
- Potential thus produced are called ..**potential barrier**
- Ge..0.3 V Si ..0.7V



PN JUNCTION WORKING MODES

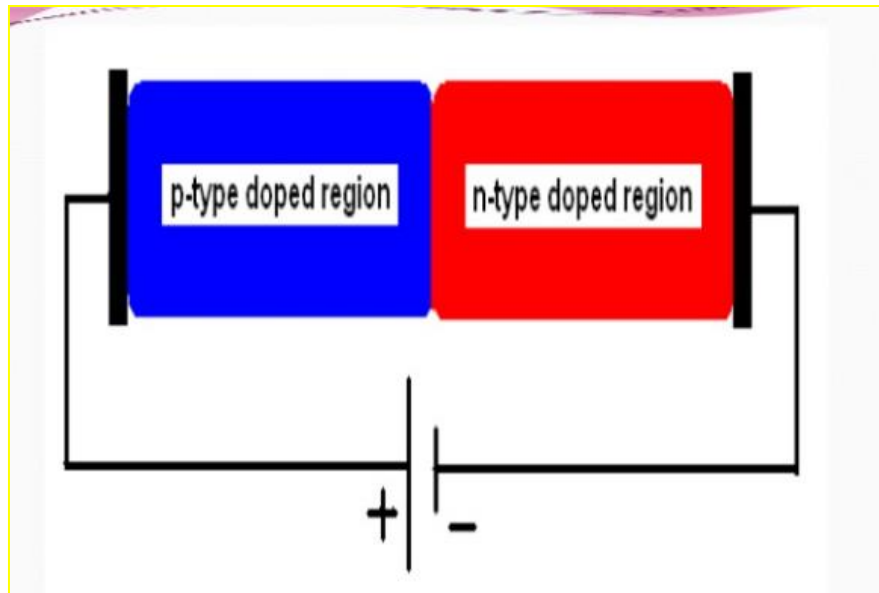
PN junction can basically work in two modes, (***A battery is connected to the diode***)

forward bias mode (positive terminal connected to p-region and negative terminal connected to n region)

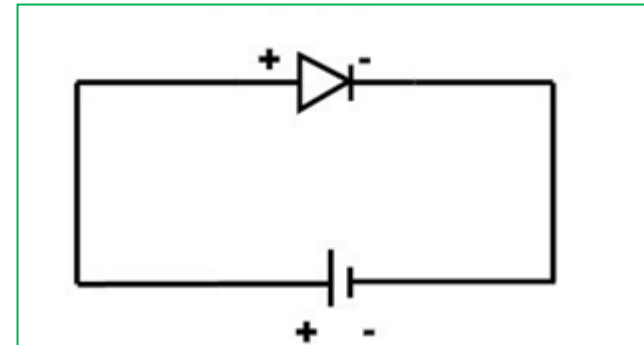
reverse bias mode (negative terminal connected to p-region and positive terminal connected to n region)

PN JUNCTION DIODE

- Forward Bias Connection

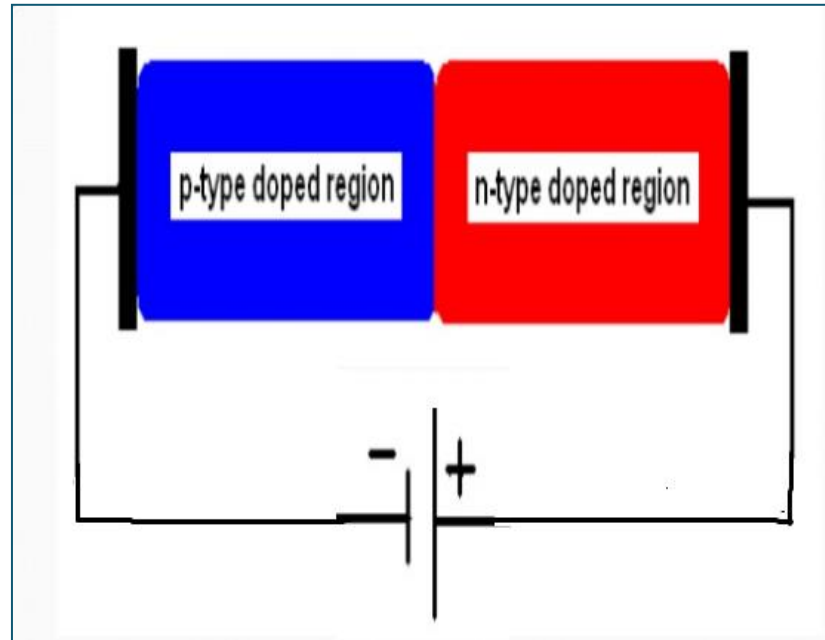


- Forward Bias Connection

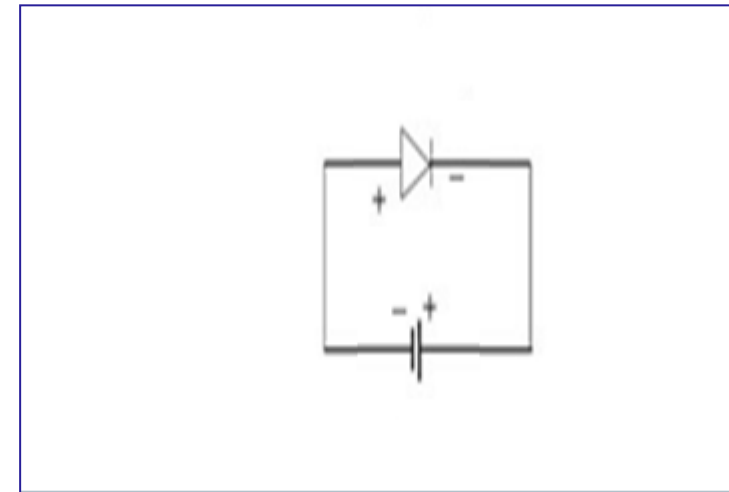


PN JUNCTION DIODE

- Reverse Bias Connection

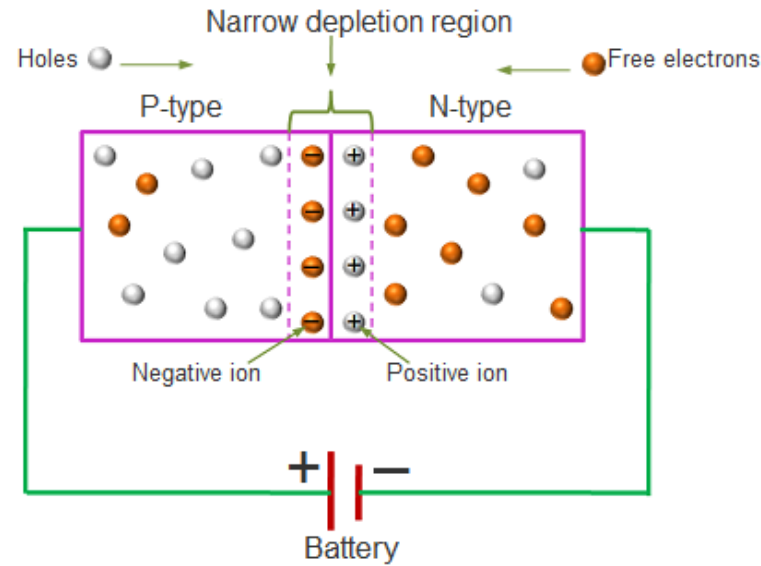
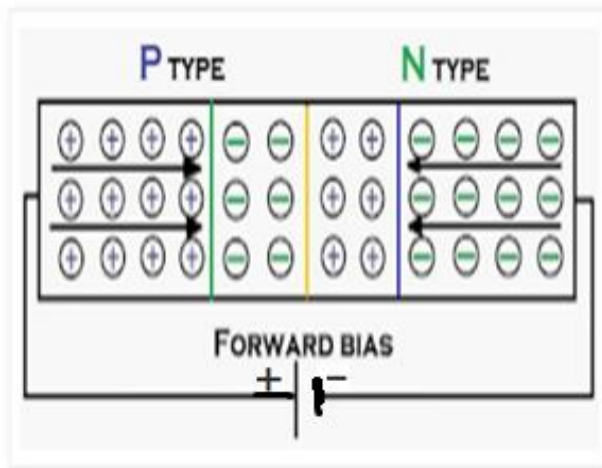


- Reverse Bias Connection



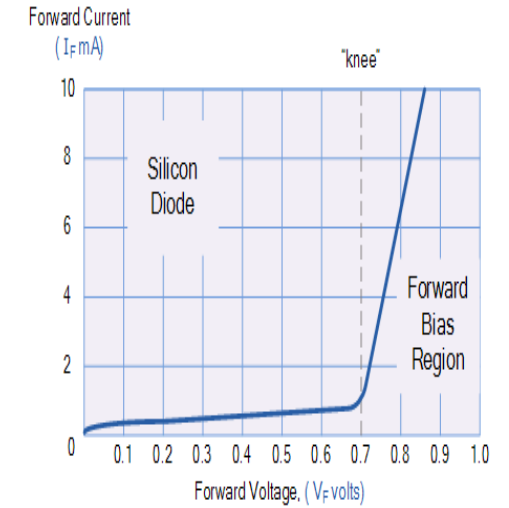
The PN Junction

- Forward Bias PN Junction Diode



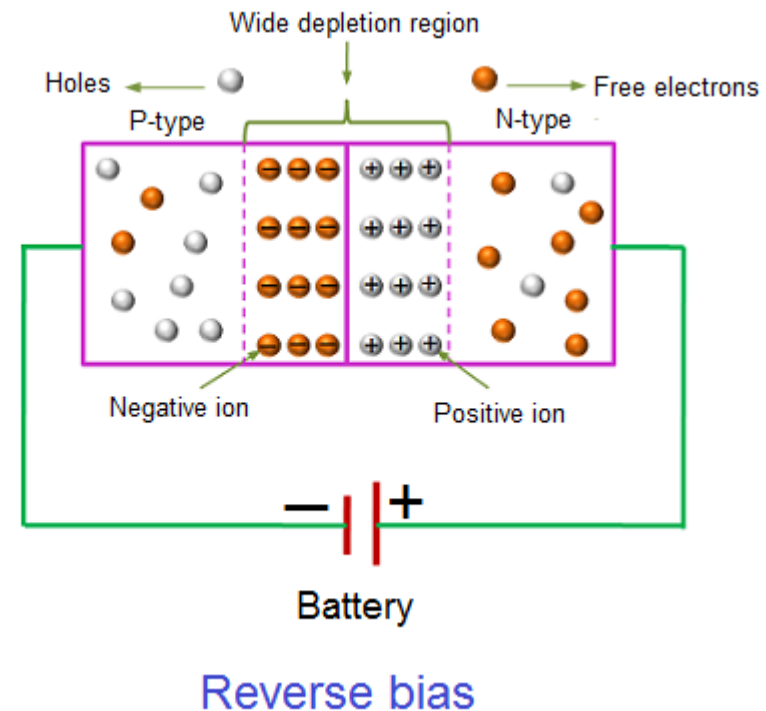
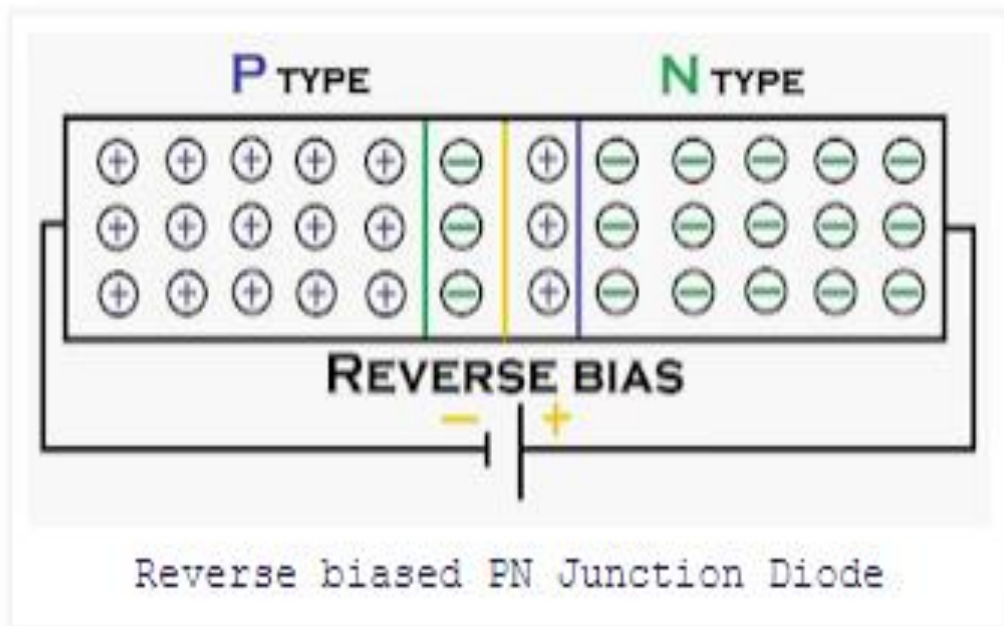
Forward bias

Forward Characteristics Curve for a Junction Diode

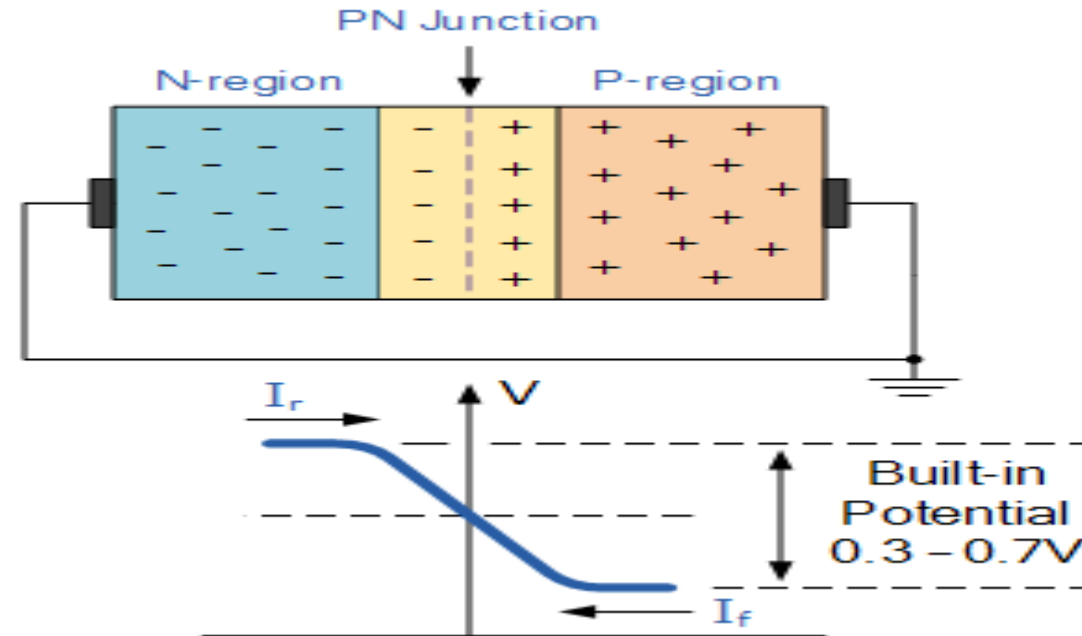


The PN Junction

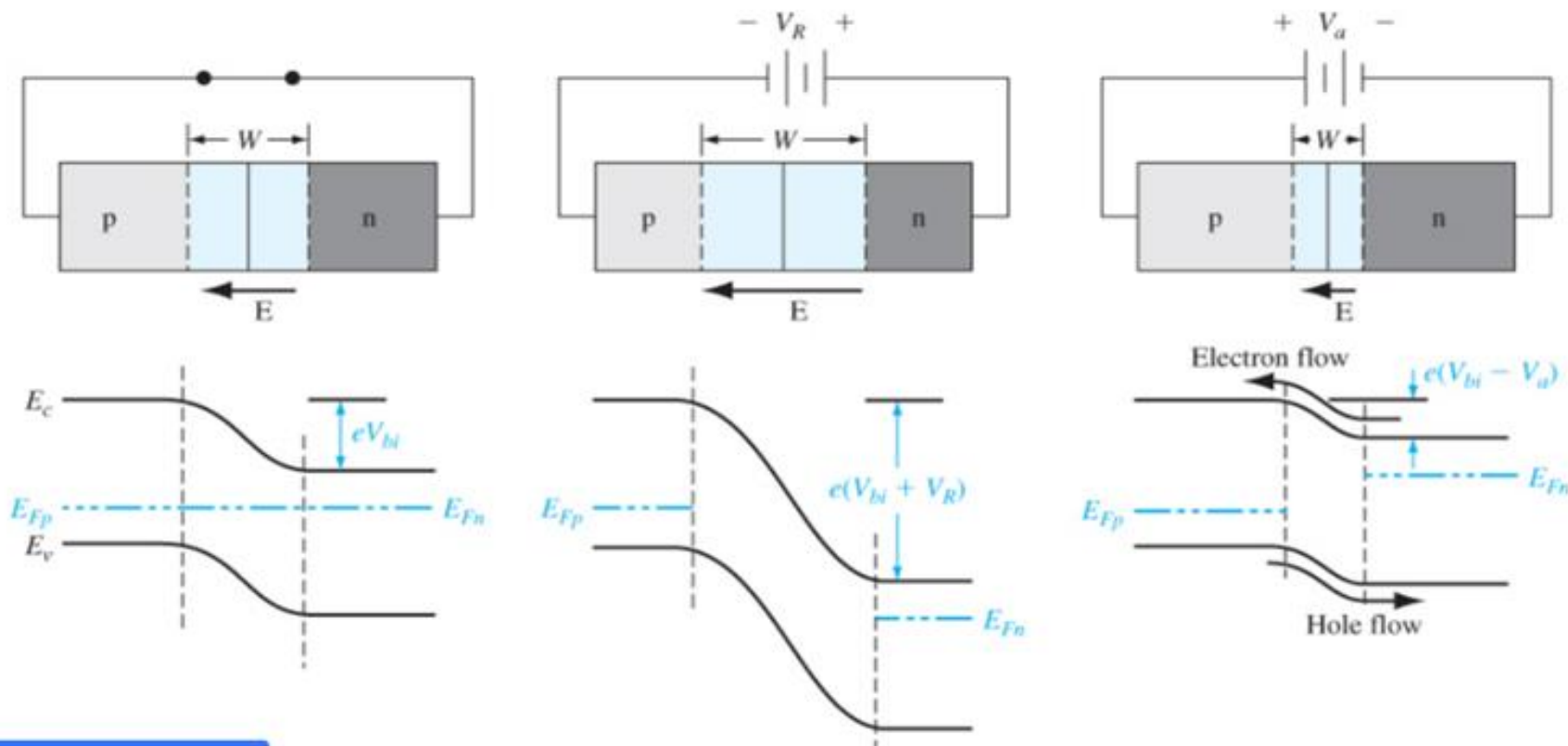
- Reverse Bias PN Junction Diode



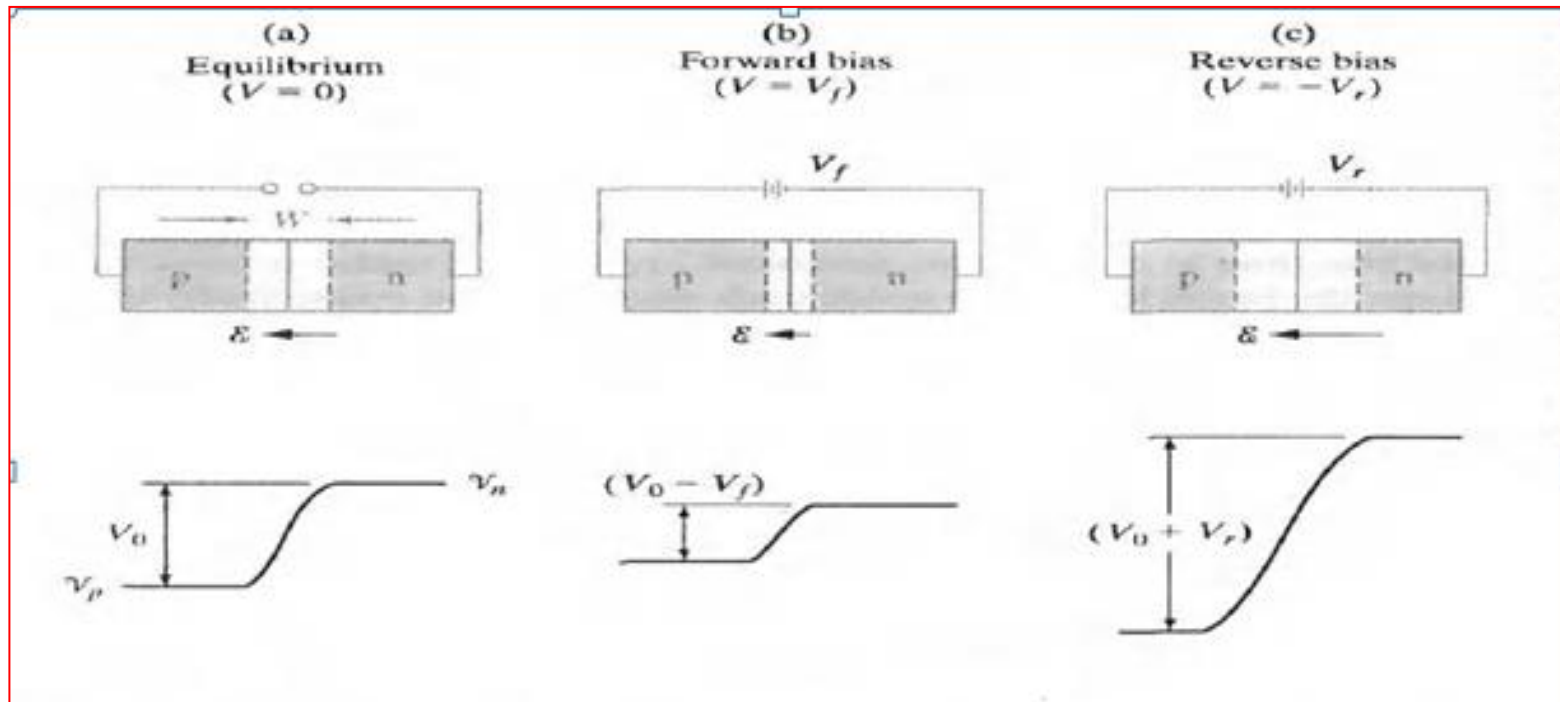
The PN Junction



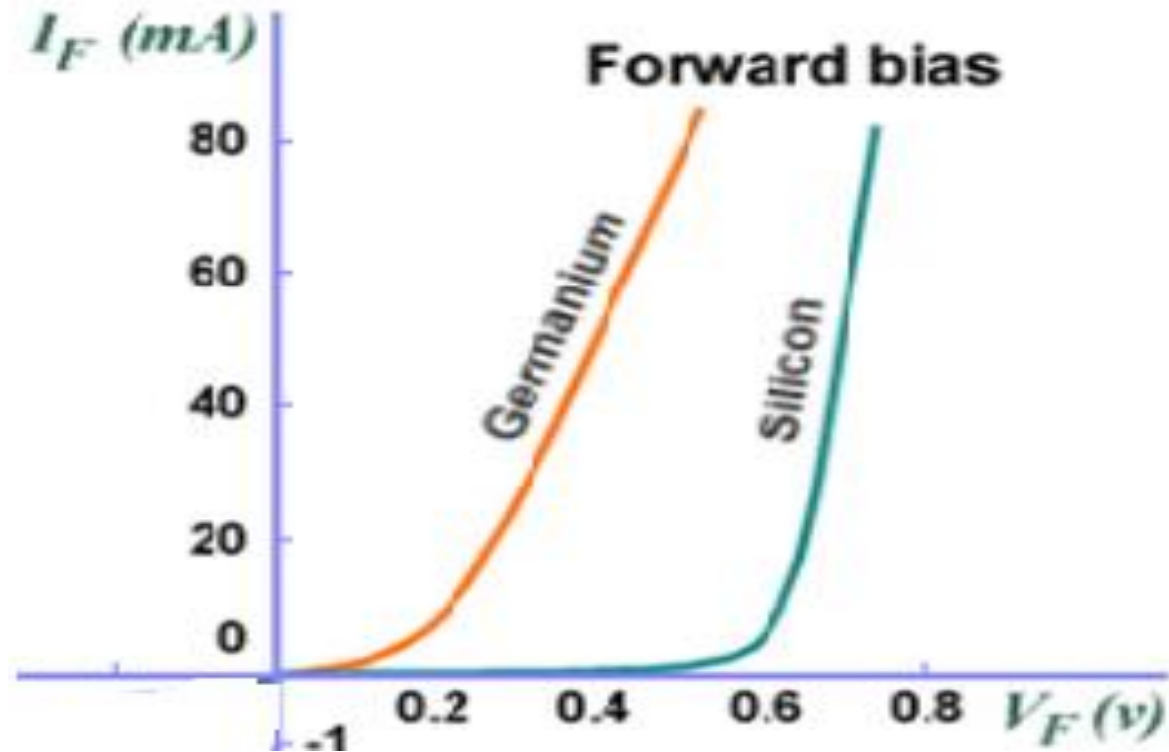
Energy Band Bending Diagram PN Junction Diode



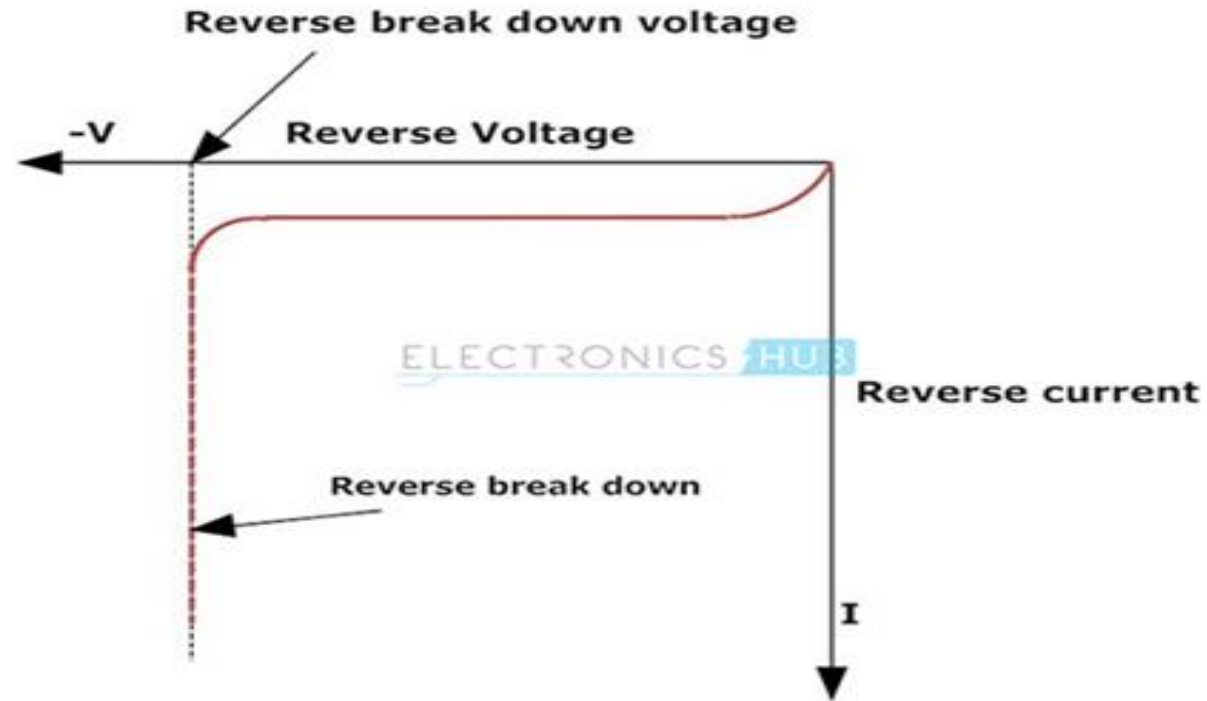
Energy Band Bending Diagram PN Junction Diode



Forward Diode Characteristics



Reverse Diode Characteristics



The PN Junction

APPLICATIONS

-as rectifiers to convert AC into DC.
- As an switch in computer circuits.
- As detectors in radios to detect audio signals
- As LED to emit different colours.

The PN Junction

Automatic switch

- When the diode is forward bias ,the switch is **CLOSED**.
- When it is reverse biased , it is **OPEN**



Thank You

HAVE A NICE DAY